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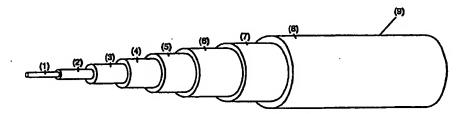
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(54) Title: AN IMPROVED LIGHTNING DOWNCONDUCTOR



(57) Abstract

A lightning downconductor (9) forming part of a lightning protection system, the downconductor (9) has an upper end connected to a lightning collector (10) through an upper termination device (11) and a lower end connected to an earthing system (15) through a lower termination (14). The downconductor (9) comprises an inner electrical conductor (3), an insulating layer (5) surrounding the inner electrical conductor (3), a resistive semi-conductive layer (6) surrounding the insulating layer (5) and a conductive layer (7) surrounding the resistive semi-conductive layer (6). A length of the conductive layer (7) is omitted or removed from the upper end of the downconductor (9) adjacent the upper termination device (11) to expose the resistive semi-conductive layer (6) as an outer layer of the downconductor (9).